

**RD3P200SN** 

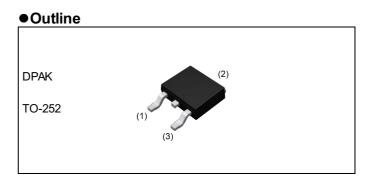
# Nch 100V 20A Power MOSFET

# Datasheet

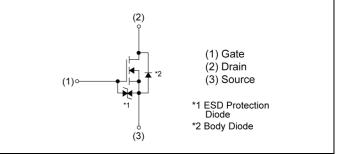
V <sub>DSS</sub>	100V
R <sub>DS(on)</sub> (Max.)	46mΩ
I <sub>D</sub>	±20A
P <sub>D</sub>	20W

# Features

- 1) Low on resistance
- 2) Fast switching speed
- 3) Drive circuits can be simple
- 4) Parallel use is easy
- 5) Pb-free lead plating ; RoHS compliant



# Inner circuit



# Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
_	Tape width (mm)	16
Туре	Quantity (pcs)	2500
	Taning and a	TL
	Taping code	TL1
	Marking	RD3P200SN

# Application

Switching

# • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

<b>U</b> ( u	• •		
Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	100	V
Continuous drain current	I <sub>D</sub> *1	±20	A
Pulsed drain current	I <sub>DP</sub> *2	±80	Α
Gate - Source voltage	V <sub>GSS</sub>	±20	V
Avalanche current, single pulse	I <sub>AS</sub> *3	10	A
Avalanche energy, single pulse	E <sub>AS</sub> *3	72	mJ
Power dissipation	P <sub>D</sub> <sup>*4</sup>	20	W
Junction temperature	Tj	150	С°
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

# •Thermal resistance

Peremeter	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	$R_{thJC}^{*4}$	-	-	6.25	°C/W

# •Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Sumbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	100	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	116.9	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	-	-	1	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	-	-	±10	μA
Gate threshold voltage	$V_{GS(th)}$	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	1.0	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-3.6	-	mV/°C
Static drain - source	<b>D</b> *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	-	33	46	
on - state resistance	$R_{DS(on)}$ *5	V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 20A	-	36	50	mΩ
Gate resistance	R <sub>G</sub>	f = 1MHz, open drain	-	4.9	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  * <sup>5</sup>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 20A	15	-	-	S



### RD3P200SN

# • Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Cumpbel	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	2100	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	180	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	120	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \simeq 50V, V_{GS} = 10V$	-	100	-	
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 10A	-	35	-	20
Turn - off delay time	$t_{d(off)}$ *5	$R_L \simeq 5\Omega$	-	150	-	ns
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	100	-	

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q <sub>g</sub> *5	V <sub>DD</sub> ≃ 50V,	-	55	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 20A,	-	5.5	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	12.5	-	

# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Cump b o l	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I <sub>S</sub> *1	T - 25°0	-	-	14	А
Pulse forward current	$I_{SP}^{*2}$	T <sub>a</sub> = 25°C	-	-	80	А
Forward voltage	V <sub>SD</sub> *5	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 10A, V <sub>GS</sub> =0V	-	53	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/µs	-	120	-	μC

\*1 Limited only by maximum temperature allowed.

\*2 Pw $\leq$ 10µs , Duty cycle $\leq$ 1%

\*3 L  $\simeq$  1mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>j</sub> = 25°C Fig.3-1,3-2

\*4 T<sub>c</sub>=25°C

\*5 Pulsed

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#### • Electrical characteristic curves

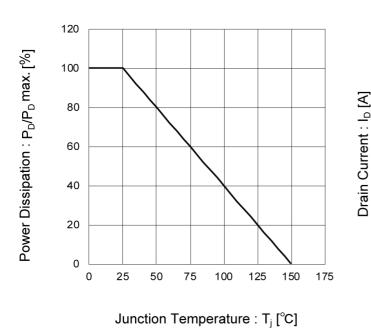


Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

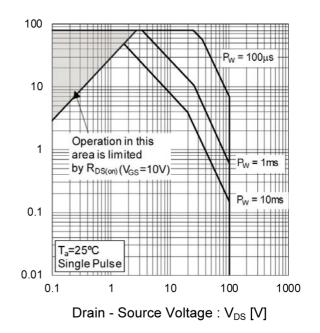
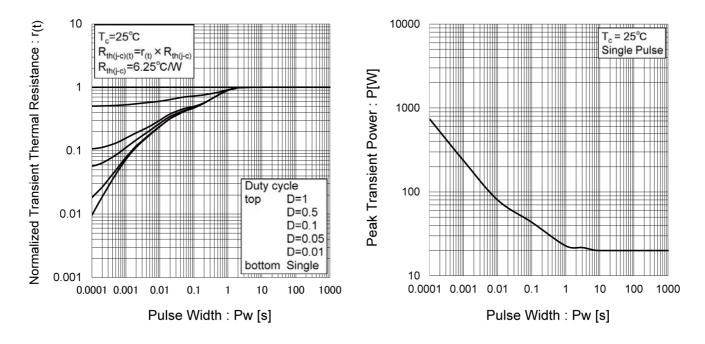


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

Fig.4 Single Pulse Maximum Power dissipation





20

15

10

5

0

0

T<sub>a</sub>=25⁰C Pulsed

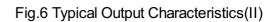
V<sub>GS</sub>=10.0V

V<sub>GS</sub>=4.0V

V<sub>GS</sub>=3.0V

0.2





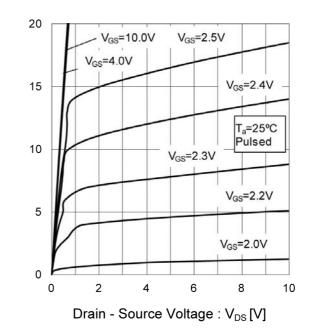
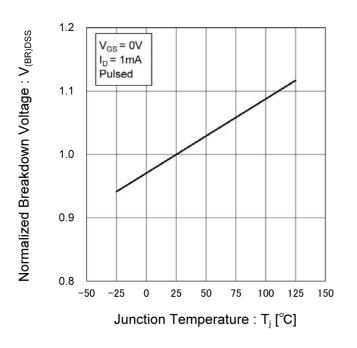


Fig.7 Breakdown Voltage vs. Junction Temperature

0.4

0.6

Drain - Source Voltage : V<sub>DS</sub> [V]





Drain Current : I<sub>D</sub> [A]

V<sub>GS</sub>=2.5V

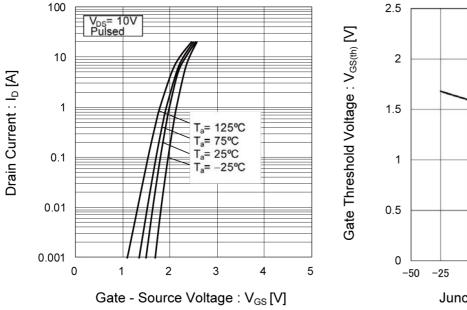
V<sub>GS</sub>=2.3V

V<sub>GS</sub>=2.2V

V<sub>GS</sub>=2.0V

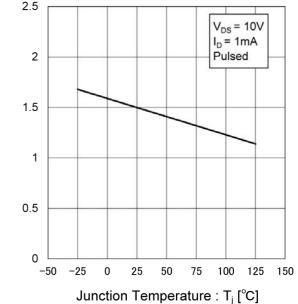
1

0.8

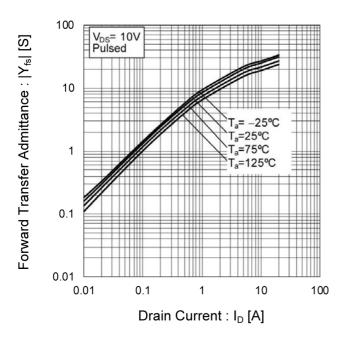


# Fig.8 Typical Transfer Characteristics

Fig.9 Gate Threshold Voltage vs. Junction Temperature



# Fig.10 Forward Transfer Admittance vs. Drain Current





# • Electrical characteristic curves

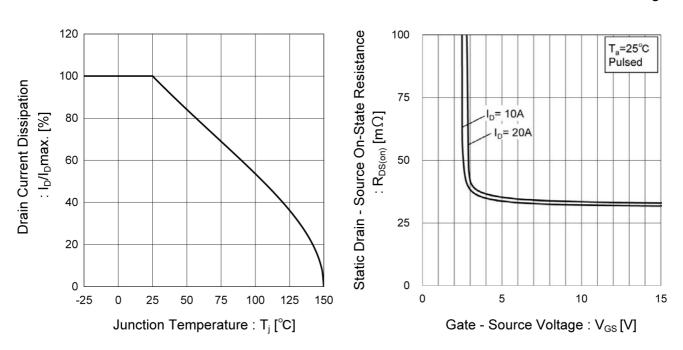


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

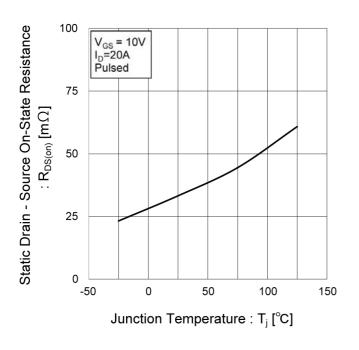




Fig.15 Static Drain - Source On - State

# • Electrical characteristic curves

Fig.14 Static Drain - Source On - State

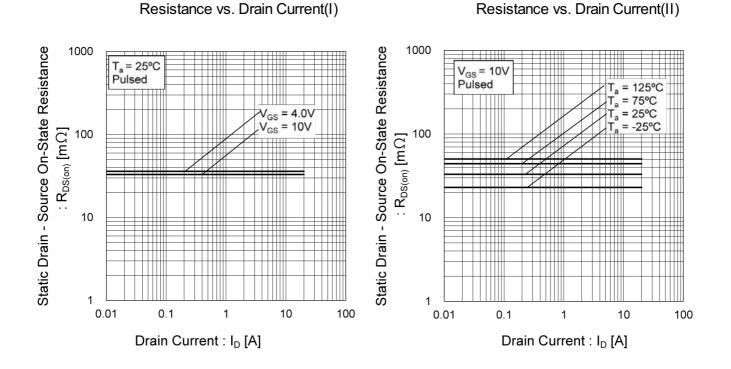
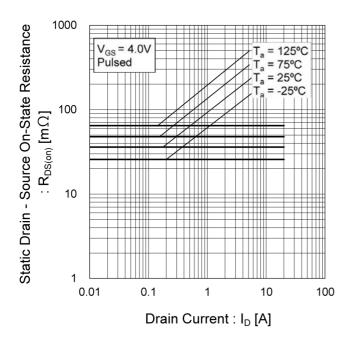
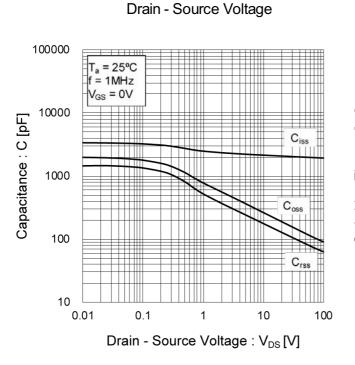


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)





# • Electrical characteristic curves



# Fig.17 Typical Capacitance vs.

Fig.18 Switching Characteristics

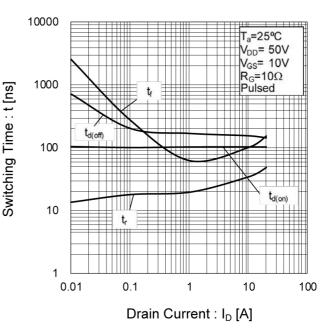


Fig.19 Dynamic Input Characteristics

Gate - Source Voltage : V<sub>GS</sub> [V]

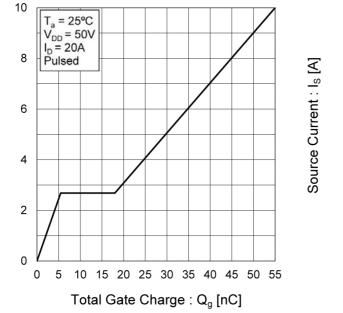
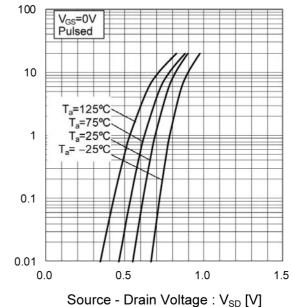


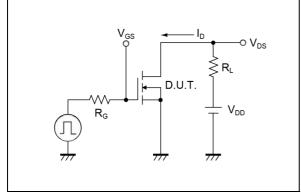
Fig.20 Source Current vs. Source Drain Voltage



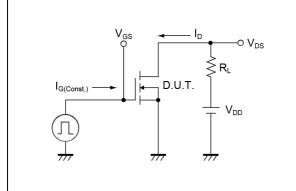


### Measurement circuits

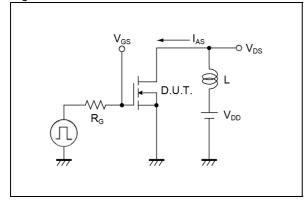




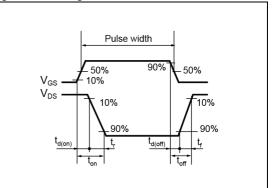
#### Fig.2-1 Gate Charge Measurement Circuit



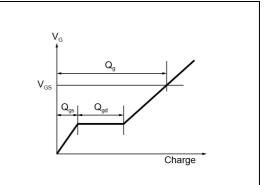
#### Fig.3-1 Avalanche Measurement Circuit



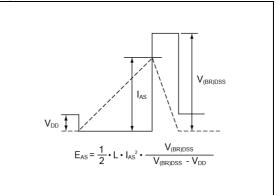
#### Fig.1-2 Switching Waveforms



#### Fig.2-2 Gate Charge Waveform

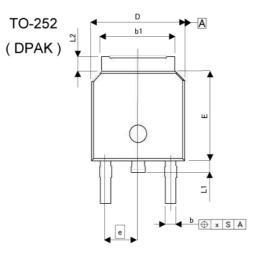


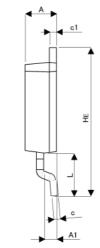
#### Fig.3-2 Avalanche Waveform

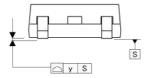


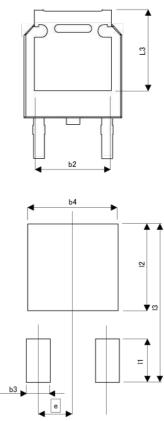


# $\bullet \textit{Dimensions}(\mathsf{TL})$









Pattern of terminal position areas [Not a recommended pattern of soldering pads]

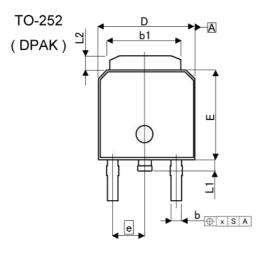
DIM -	MILIME	ETERS	INC	HES	
	MIN	MAX	MIN	MAX	
A	2.10	2.30	0.083	0.091	
A1	0.70	1.10	0.028	0.043	
b	0.65	0.85	0.026	0.033	
b1	5.10	5.40	0.201	0.213	
b2	5.	10	0.2	201	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.40	6.80	0.252	0.268	
е	2.	30	0.0	)91	
E	6.00	6.40	0.236	0.252	
HE	9.50	10.50	0.374	0.413	
L	2.90		0.1	14	
L1	0.70	0.90	0.028	0.035	
L2	0.70	1.30	0.028	0.051	
L3	5.	5.30		0.209	
х	-	0.10	14	0.004	
у	-	0.10	-	0.004	

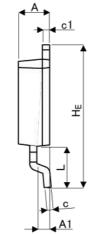
DIM -	MILIME	ETERS	INCHES	
	MIN	MAX	MIN	MAX
b3	<u>8</u>	1.10	64 <u>28</u>	0.043
b4	×	5.40	3 <del></del> )	0.213
11	<u>12</u>	2.90	7 <u>6</u>	0.114
12		5.50	(. <del></del> )	0.217
13	<u>19</u>	10.50	021	0.413

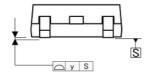
Dimension in mm/inches

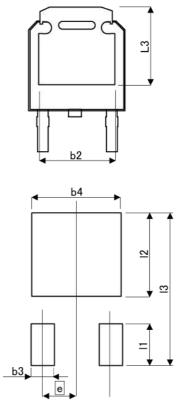


# • Dimensions (TL1)









Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM -	MILIME	ETERS	INC	HES
	MIN	MAX	MIN	MAX
A	2.20	2.40	0.087	0.094
A1	0.70	1.10	0.028	0.043
b	0.60	0.90	0.024	0.035
b1	5.20	5.50	0.205	0.217
b2	4.	80	0.1	89
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.40	6.80	0.252	0.268
е	2.	30	0.0	)91
E	6.00	6.40	0.236	0.252
HE	9.40	10.40	0.370	0.409
L	2.	90	0.1	14
L1	0.60	1.00	0.024	0.039
L2	0.70	1.30	0.028	0.051
L3	5.30		0.2	209
х	÷ (	0.25		0.010
у	2	0.10	(7)	0.004
DIM -	MILIME	MILIMETERS		HES
	MIN	MAX	MIN	MAX
b3	×	1.15	(#)	0.045
b4	≂	5.55	0.753	0.219
11	÷ ()	2.77		0.109
12		5.50	(E))	0.217
13	-	10.40	280	0.409

Dimension in mm/inches



# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications
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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ		CLASSⅢ	

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  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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